




## Thyristor/Diode and Thyristor/Thyristor (SUPER MAGN-A-PAK Power Modules), 500 A



SUPER MAGN-A-PAK

### FEATURES

- High current capability
- High surge capability
- Industrial standard package
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- UL approved file E78996 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



RoHS COMPLIANT

### PRODUCT SUMMARY

$I_{T(AV)}$ , $I_{F(AV)}$	500 A
---------------------------	-------

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{T(AV)}$ , $I_{F(AV)}$	82 °C	500	A
$I_{T(RMS)}$		785	A
	$T_C$	82	°C
$I_{TSM}$	50 Hz	17.8	kA
	60 Hz	18.7	
$I^2t$	50 Hz	1591	kA <sup>2</sup> s
	60 Hz	1452	
$I^2\sqrt{t}$		15 910	kA <sup>2</sup> √s
$V_{RRM}$	Range	800 to 1600	V
$T_{Stg}$	Range	- 40 to 150	°C
$T_J$	Range	- 40 to 130	

### ELECTRICAL SPECIFICATIONS

#### VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	$V_{RRM}/V_{DRM}$ , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}/I_{DRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VSK.500	08	800	900	100
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

ON-STATE CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$ , $I_{F(AV)}$	180° conduction, half sine wave		500	A
				82	°C
Maximum RMS on-state current	$I_{T(RMS)}$	180° conduction, half sine wave at $T_C = 82\text{ °C}$		785	A
Maximum peak, one-cycle, non-repetitive on-state surge current	$I_{TSM}$ , $I_{FSM}$	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	kA
		t = 8.3 ms			
		t = 10 ms	100 % $V_{RRM}$ reappplied		
		t = 8.3 ms			
Maximum $I^2t$ for fusing	$I^2t$	t = 10 ms	No voltage reappplied	1591	kA <sup>2</sup> s
		t = 8.3 ms			
		t = 10 ms	100 % $V_{RRM}$ reappplied	1452	
		t = 8.3 ms		1125	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reappplied		1027	kA <sup>2</sup> √s
Low level value or threshold voltage	$V_{T(TO)1}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_J$ maximum		15910	V
High level value of threshold voltage	$V_{T(TO)2}$	(I $> \pi \times I_{T(AV)}$ ), $T_J = T_J$ maximum		0.85	
Low level value on-state slope resistance	$r_{t1}$	(16.7 % $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_J$ maximum		0.93	mΩ
High level value on-state slope resistance	$r_{t2}$	(I $> \pi \times I_{T(AV)}$ ), $T_J = T_J$ maximum		0.36	
Maximum on-state voltage drop	$V_{TM}$	$I_{pk} = 1500\text{ A}$ , $T_J = 25\text{ °C}$ , $t_p = 10\text{ ms}$ sine pulse		1.50	V
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 1500\text{ A}$ , $T_J = 25\text{ °C}$ , $t_p = 10\text{ ms}$ sine pulse		1.50	V
Maximum holding current	$I_H$	$T_J = 25\text{ °C}$ , anode supply 12 V resistive load		500	mA
Maximum latching current	$I_L$			1000	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum rate of rise of turned-on current	$di/dt$	$T_J = T_J$ maximum, $I_{TM} = 400\text{ A}$ , $V_{DRM}$ applied		1000	A/μs
Typical delay time	$t_d$	Gate current 1 A, $di_g/dt = 1\text{ A}/\mu\text{s}$ $V_d = 0.67\% V_{DRM}$ , $T_J = 25\text{ °C}$		2.0	μs
Typical turn-off time	$t_q$	$I_{TM} = 750\text{ A}$ ; $T_J = T_J$ maximum, $di/dt = -60\text{ A}/\mu\text{s}$ , $V_R = 50\text{ V}$ , $dV/dt = 20\text{ V}/\mu\text{s}$ , gate 0 V 100 Ω		200	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum critical rate of rise of off-state voltage	$dV/dt$	$T_J = 130\text{ °C}$ , linear to $V_D = 80\% V_{DRM}$		1000	V/μs
RMS insulation voltage	$V_{INS}$	t = 1 s		3000	V
Maximum peak reverse and off-state leakage current	$I_{RRM}$ , $I_{DRM}$	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied		100	mA



# VSKT500-..PbF, VSKH500-..PbF, VSKL500-..PbF

Thyristor/Diode and Thyristor/Thyristor Vishay Semiconductors  
(SUPER MAGN-A-PAK Power Modules), 500 A

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms	10	W
Maximum peak average gate power	$P_{G(AV)}$	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$	2.0	
Maximum peak positive gate current	$+I_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms	3.0	A
Maximum peak positive gate voltage	$+V_{GM}$		20	V
Maximum peak negative gate voltage	$-V_{GM}$		5.0	
Maximum DC gate current required to trigger	$I_{GT}$	$T_J = 25$ °C, $V_{ak} 12$ V	200	mA
DC gate voltage required to trigger	$V_{GT}$		3.0	V
DC gate current not to trigger	$I_{GD}$	$T_J = T_J$ maximum	10	mA
DC gate voltage not to trigger	$V_{GD}$		0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	$T_J$		- 40 to 130	°C
Maximum storage temperature range	$T_{Stg}$		- 40 to 150	
Maximum thermal resistance, junction to case per junction	$R_{thJC}$	DC operation	0.065	K/W
Maximum thermal resistance, case to heatsink	$R_{thC-hs}$		0.02	
Mounting torque $\pm 10$ %	SMAP to heatsink busbar to SMAP	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	6 to 8	Nm
			12 to 15	
Approximate weight			1500	g
Case style		See dimensions - link at the end of datasheet	SUPER MAGN-A-PAK	

$\Delta R_{thJC}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011		
90°	0.014	0.015		
60°	0.021	0.022		
30°	0.037	0.038		

**Note**

- Table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

# VSKT500-..PbF, VSKH500-..PbF, VSKL500-..PbF



Vishay Semiconductors Thyristor/Diode and Thyristor/Thyristor  
(SUPER MAGN-A-PAK Power Modules), 500 A

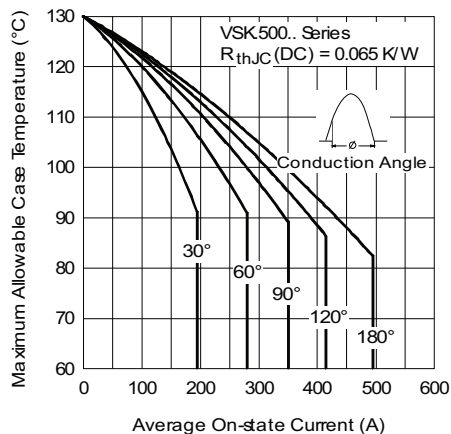


Fig. 1 - Current Ratings Characteristics

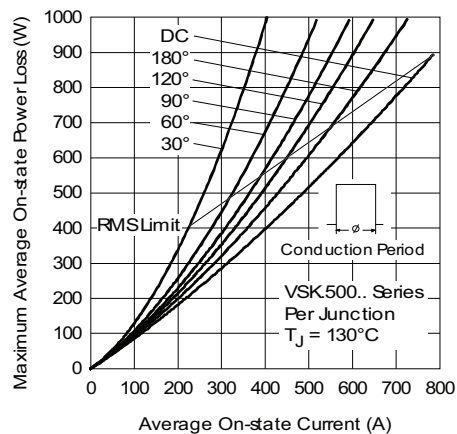


Fig. 4 - On-State Power Loss Characteristics

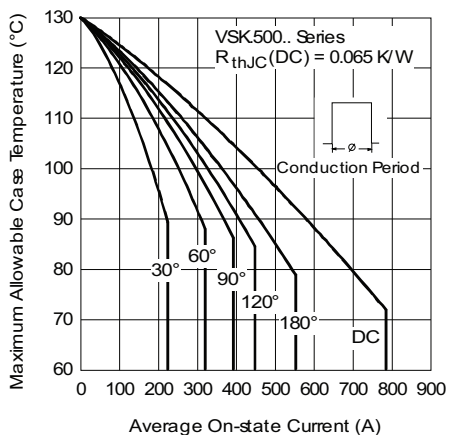


Fig. 2 - Current Ratings Characteristics

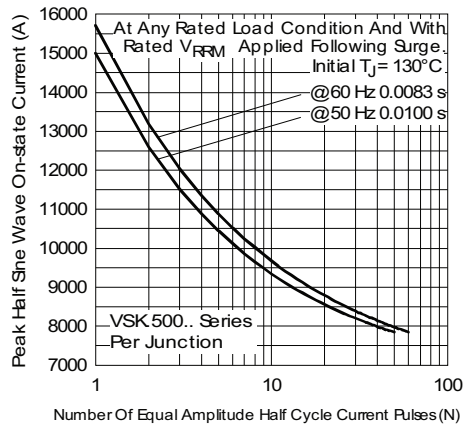


Fig. 5 - Maximum Non-Repetitive Surge Current

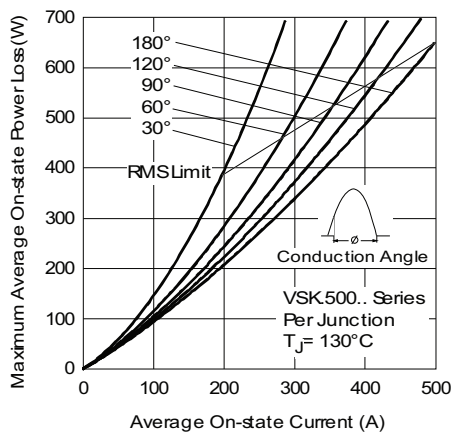


Fig. 3 - On-State Power Loss Characteristics

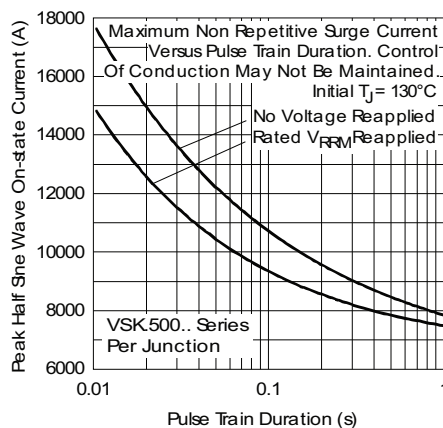


Fig. 6 - Maximum Non-Repetitive Surge Current



# VSKT500-..PbF, VSKH500-..PbF, VSKL500-..PbF

Thyristor/Diode and Thyristor/Thyristor Vishay Semiconductors  
(SUPER MAGN-A-PAK Power Modules), 500 A

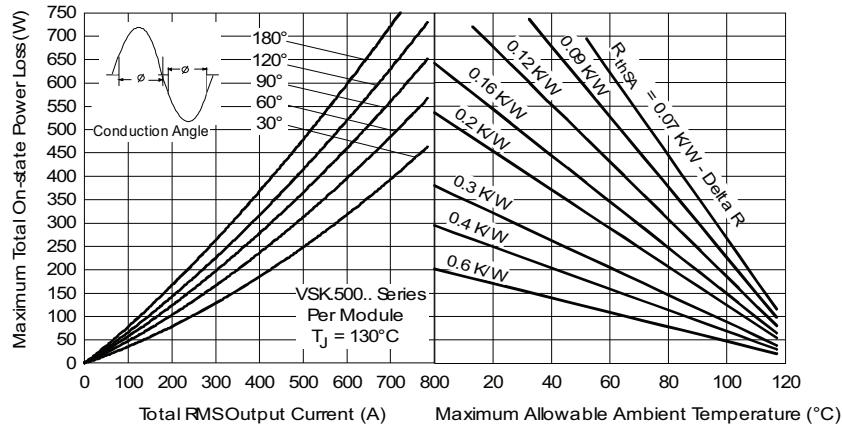


Fig. 7 - On-State Power Loss Characteristics

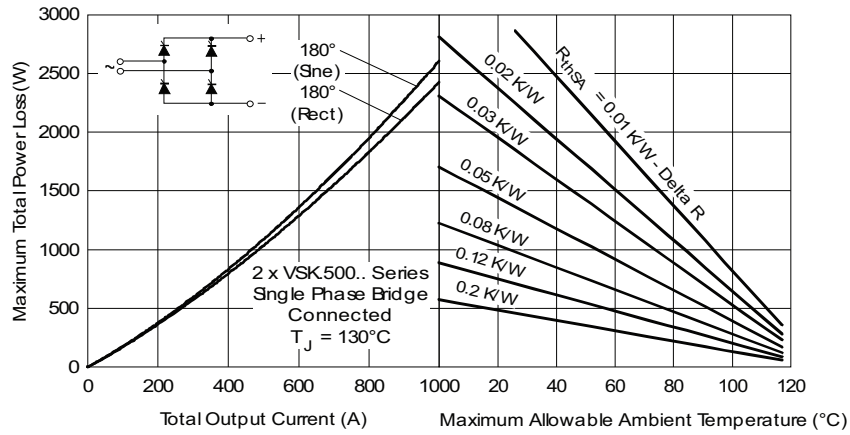


Fig. 8 - On-State Power Loss Characteristics

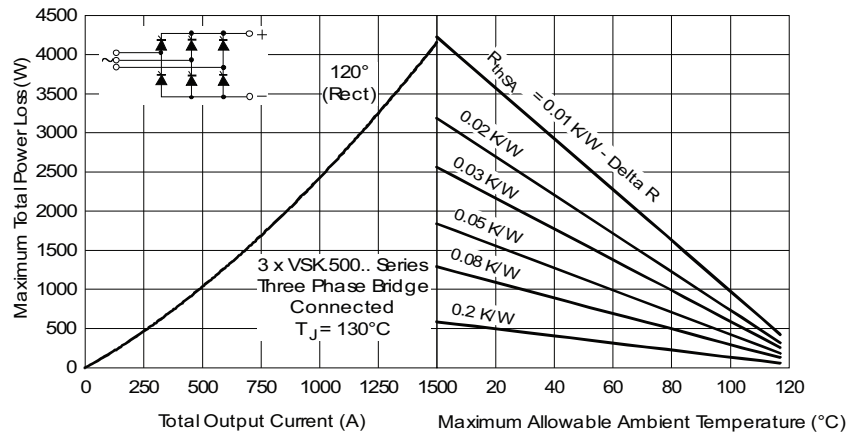


Fig. 9 - On-State Power Loss Characteristics

# VSKT500-..PbF, VSKH500-..PbF, VSKL500-..PbF



Vishay Semiconductors Thyristor/Diode and Thyristor/Thyristor  
(SUPER MAGN-A-PAK Power Modules), 500 A

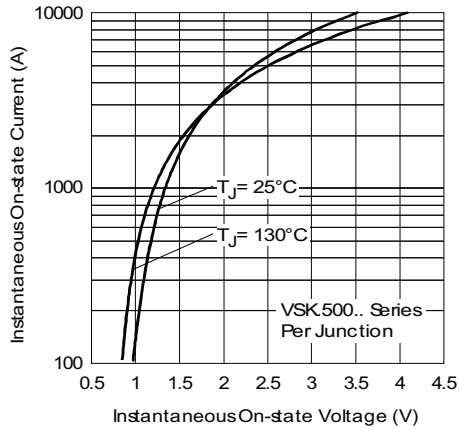


Fig. 10 - On-State Voltage Drop Characteristics

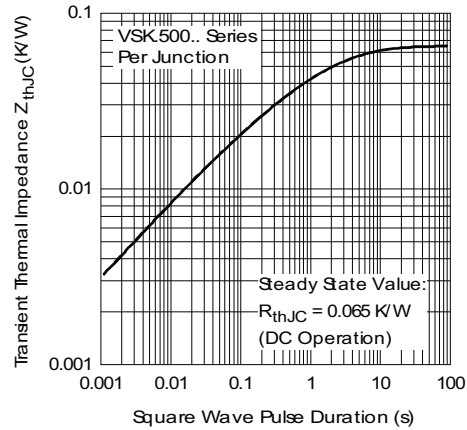


Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristics

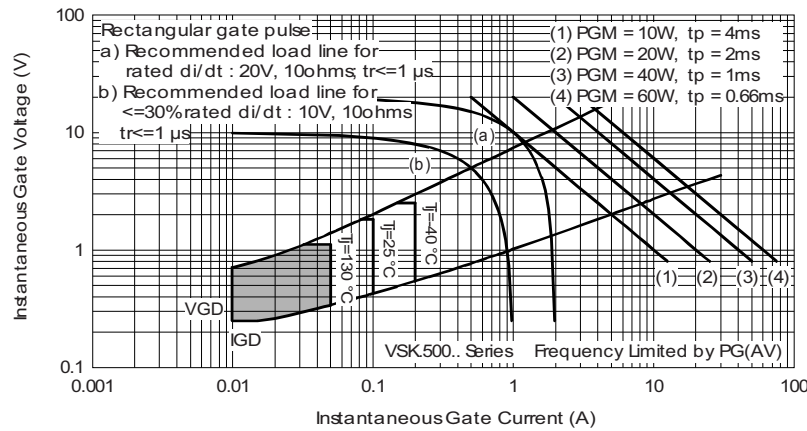


Fig. 12 - Gate Characteristics

## ORDERING INFORMATION TABLE

Device code	<b>VSK</b>	<b>T</b>	<b>500</b>	<b>-</b>	<b>16</b>	<b>PbF</b>
	①	②	③		④	⑤
	①	-	Module type			
	②	-	Circuit configuration (see end of datasheet)			
	③	-	Current rating			
	④	-	Voltage code x 100 = $V_{RRM}$ (see Voltage Ratings table)			
	⑤	-	Lead (Pb)-free			

### Note

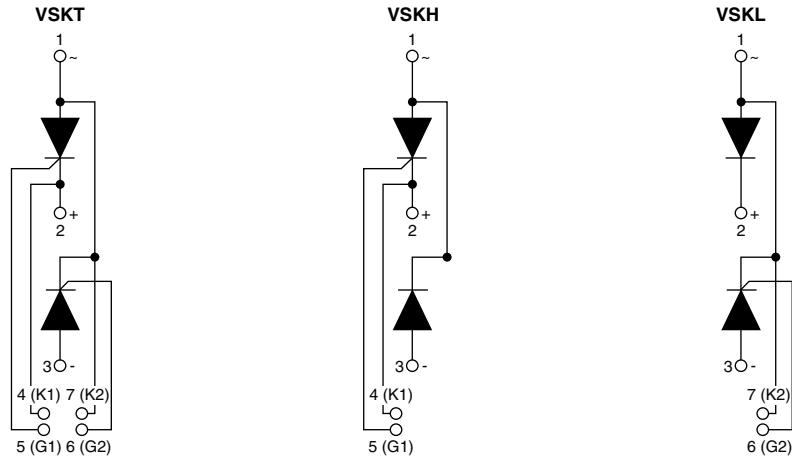
- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)



# VSKT500-..PbF, VSKH500-..PbF, VSKL500-..PbF

Thyristor/Diode and Thyristor/Thyristor Vishay Semiconductors  
(SUPER MAGN-A-PAK Power Modules), 500 A

## CIRCUIT CONFIGURATION



### LINKS TO RELATED DOCUMENTS

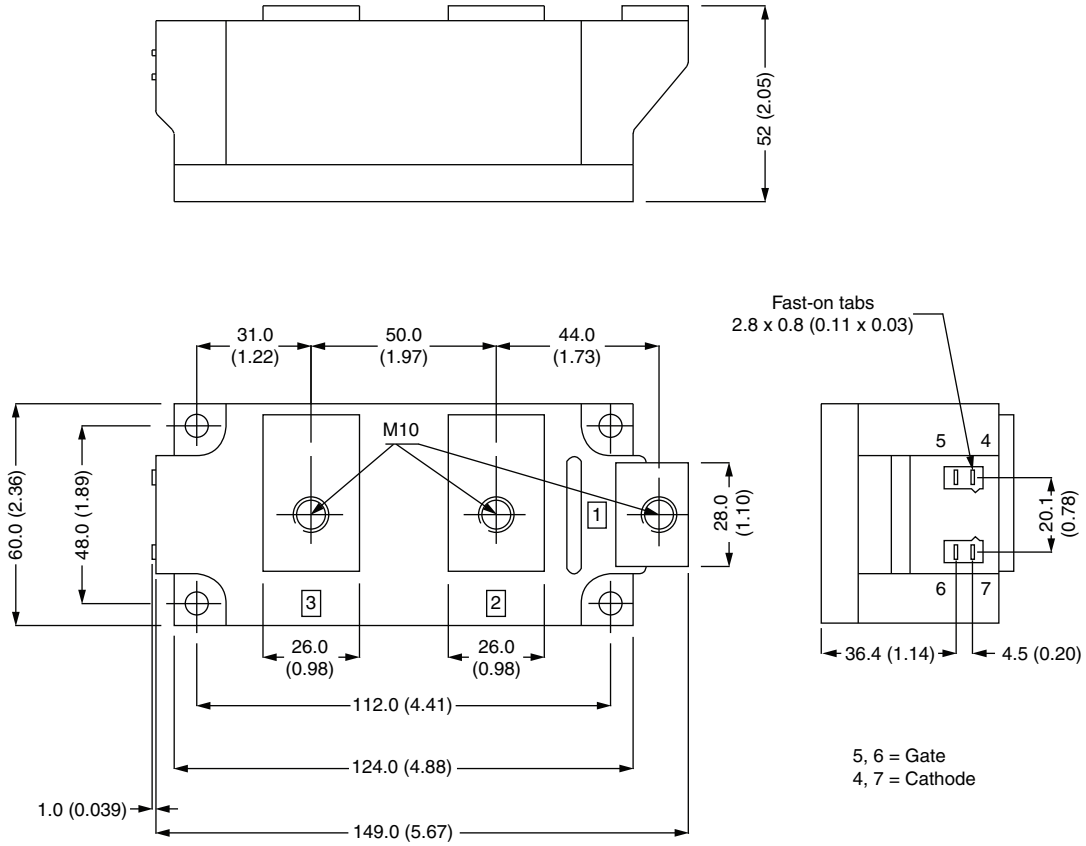
Dimensions

[www.vishay.com/doc?95283](http://www.vishay.com/doc?95283)



### Super MAGN-A-PAK Thyristor/Diode

**DIMENSIONS** in millimeters (inches)







## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)